## Exercises for Lecture Course on Modeling and System Identification (MSI) Albert-Ludwigs-Universität Freiburg – Winter Term 2017

## **Exercise 2: Linear Least Squares Introduction**

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In this exercise, you will discover basic properties of the linear least squares estimation method, as well as the covariance operator.

## Exercise Tasks

1. The covariance matrix of a vector-valued random variable X in  $\mathbb{R}^n$  with mean  $\mathbb{E} \{X\} = \mu_X$  is defined by

$$\operatorname{cov}(X) \coloneqq \mathbb{E}\left\{ (X - \mu_X) (X - \mu_X)^{\mathrm{T}} \right\}.$$

Prove that the covariance matrix of a vector-valued variable Y = AX + b with constant  $A \in \mathbb{R}^{m \times n}$  and  $b \in \mathbb{R}^m$  is given by

$$\operatorname{cov}\left(Y\right) = A \, \operatorname{cov}\left(X\right) A^{\mathrm{T}}.$$

- 2. Suppose you are measuring a constant  $x \in \mathbb{R}$  perturbed by Gaussian, zero-mean noise  $\epsilon \in \mathbb{R}$   $(\epsilon \sim \mathcal{N}(0, \sigma^2))$ . Prove that the LLS estimate for this constant is the sample mean.
- 3. A semiconductor diode is a crystalline piece of semiconductor material with a p-n junction connected to two electrical terminals. In the most common form it consists of a p-n doped silicon substrate. The Shockley equation

$$I_d = I_s \left( e^{\frac{qU}{mk_BT}} - 1 \right),$$

where U is the applied voltage in forward direction, m is the ideality factor, q is the elementary charge,  $k_B$  is the Boltzmann constant and T is the temperature, is used to describe the diode current  $I_d$  flowing through the diode in forward direction.

Let's consider current-voltage data of a common silicon diode following the Shockley equation. This data is available on the course page in a matlab data file called Data.mat. (5 points)

- (a) Plot the diode current  $I_d$  [mA] (second column) vs. the applied voltage U [mV] (first column) data, with voltage along the x-axis and current along the y-axis. When looking at the data for current as a function of voltage, what is the lowest order polynomial relation that you would expect to give a meaningful linear least squares fit? What form does this relation take? (Hint: remember that linear least squares does not necessarily require a linear relationship between  $I_d$  and U.) (1 point)
- (b) Which properties should the data fulfil, for linear least squares to be an appropriate estimation method? Make those assumptions for the following questions. (0.5 points)
- (c) Choose  $y \in \mathbb{R}^N$ ,  $\phi_i \in \mathbb{R}^{1 \times d}$  and  $\Phi \in \mathbb{R}^{N \times d}$ , to correspond to the linear least squares problem form. (1.5 points)
- (d) Is  $\Phi^{T}\Phi$  invertible? Why? What could lead to non-invertability? Does Matlab return a warning, if you attempt to invert this matrix? Why would it? (1 point)

- (e) In general, it is not advised to use a linear system solve, using the pseudo-inverse, for problems that have this (see 3d) behavior. Try it anyways. Plot the estimated currents as a function of voltage in your data-plot, and consider the coefficients of the fitted polynomial. Do these coefficients appear reasonable? (Hint: use the backslash operator in the linear system solve.) (0.5 points)
- (f) Reconsider your fitting problem, using units of [A] for  $I_d$  and [V] for U. Apply a linear system solve with the pseudo-inverse to this problem. Add this estimate to the data-plot, and consider the coefficients of the fitted polynomial. Does scaling the measurements improve the performance of linear least squares? Why? (0.5 points)